NSN 5961-01-059-5970

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-059-5970 **Inclosure Material:** Ceramic **Overall Length:** Between 0.515 inches and 0.565 inches **Overall Diameter:** Between 1.600 inches and 1.656 inches **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 400.00 amperes collector current, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0